MAC15 Series TRIAC - 400V - 800V

Maximum Ratings (TJ = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit	
Peak Repetitive Off-State Voltage (Note 1) (Gate Open, Sine Wave 50 to 60 Hz, T _J = -40° to 125°C)	MAC15A6G MAC15-8G, MAC15A8G MAC15-10G, MAC15A10G	V _{DRM} , V _{RRM}	400 600 800	V
On-State RMS Current (Full Cycle Sine Wave, 50 to 60 H:	$z, T_{c} = 80^{\circ}C)$	I _{T (RMS)}	15	А
Peak Non-Repetitive Surge Current (One Full Cycle Sine Non-Repetitive Surge Sine Non-Reptitive S	Nave, 60 Hz, $T_c = 80$ °C)	I _{TSM}	150	А
Peak Gate Voltage (Pulse Width \leq 1.0 µsec; $T_c = 90$ °C)		V_{GM}	10	V
Circuit Fusing Consideration (t = 8.3 ms)		l²t	93	A²sec
Peak Gate Power ($T_c = 80^{\circ}\text{C}$, Pulse Width = 1.0 µs)		P_{GM}	20	W
Peak Gate Current (Pulse Width $\leq 1.0 \mu sec; T_c = 90^{\circ}C$)		I _{GM}	2.0	А
Average Gate Power (t = 8.3 ms, $T_c = 80$ °C)		P _{G (AV)}	0.5	W
Operating Junction Temperature Range	T_{J}	-40 to +125	°C	
Storage Temperature Range		T _{stg}	-40 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the

Thermal Characteristics

Rating		Symbol	Value	Unit
Thermal Resistance,	Junction-to-Case (AC) Junction-to-Ambient	R _{ejc} R _{eja}	2.0 62.5	°C/W
Maximum Lead Temperature for Soldering Purpose	s, 1/8" from case for 10 seconds	T_L	260	°C

Electrical Characteristics - OFF (TJ = 25°C unless otherwise noted; Electricals apply in both directions)

Characteristic		Symbol	Min	Тур	Max	Unit
Peak Repetitive Blocking Current	T ₁ = 25°C	I _{DRM} ,	-	-	0.01	mΛ
$(V_D = V_{DRM} = V_{RRM}; Gate Open)$	T _J = 125°C	I _{RRM}	-	-	2.0	mA

Electrical Characteristics - ON (TJ = 25°C unless otherwise noted; Electricals apply in both directions)

Characteristic			Min	Тур	Max	Unit
Peak On-State Voltage (Note 2) (I _{TM} = ±21 A Peak)		V_{TM}	-	1.3	1.6	V
0 + T' 0 +	MT2(+), G(+)		-	-	50	
Gate Trigger Current (Continuous dc)	MT2(+), G(-)		-	-	50	mA
$(V_D = 12 \text{ V}, R_I = 100 \Omega)$	MT2(-), G(-)	GT	-	-	50	IIIA
$(v_D - 12 v, H_L - 100 \Omega)$	MT2(-), G(+)		-	-	75	
0 . T: 1/4	MT2(+), G(+)		-	0.9	2	
Gate Trigger Voltage (Continuous dc)	MT2(+), G(-)	\/	-	0.9	2	V
$(V_D = 12 \text{ V}, R_I = 100 \Omega)$	MT2(-), G(-)	V _{GT}	-	1.1	2	V
$(V_D - 12 V, 11_L - 100 \Omega)$	MT2(-), G(+)		-	1.4	2.5	
O . N . T:	MT2(+), G(+)		0.2	-	-	
Gate Non-Trigger Voltage	MT2(+), G(-)	\/	0.2	-	-	V
$(T_J = 110^{\circ}C)$ $(V_D = 12 \text{ V}, R_I = 100 \Omega)$	MT2(-), G(-)	V_{GD}	0.2	-	-	V
$(V_D - 12 V, H_L - 100 \Omega)$	MT2(-), G(+)		0.2	-	-	
Holding Current ($V_D = 12 V_{dc'}$ Gate Open, Initiating Current = ±200 mA))		l _H	-	6.0	40	mA
Turn-On Time (VD = Rated VDRM, ITM = 17 A) (IGT = 120 mA, Rise Time = 0.1 μs, Pulse Width = 2 μs)		tgt	-	1.5	-	μs



Recommended Operating Conditions may affect device reliability.

1. V_{ISBM} and V_{ISBM} for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; however, positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

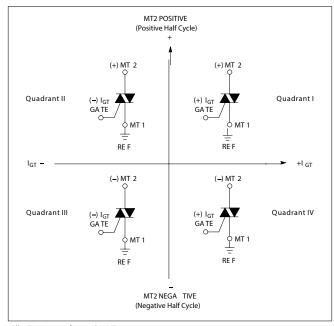
Dynamic Characteristics

Characteristic	Symbol	Min	Тур	Max	Unit
Critical Rate of Rise of Commutation Voltage ($V_D = Rated V_{DRM}$, $I_{TM} = 21 A$, Commutating di/dt = 7.6 A/ms, Gate Unenergized, $I_C = 80^{\circ}C$)	dV/dt	_	5.0	_	V/µs

Voltage Current Characteristic of SCR

Symbol	Parameter
V_{DRM}	Peak Repetitive Forward Off State Voltage
I _{DRM}	Peak Forward Blocking Current
$V_{_{\mathrm{RRM}}}$	Peak Repetitive Reverse Off State Voltage
I _{RRM}	Peak Reverse Blocking Current
V_{TM}	Maximum On State Voltage
I _H	Holding Current

Quadrant Definitions for a Triac



All polarities are referenced to MT1.
With in-phase signals (using standard AC lines) quadrants I and III are used

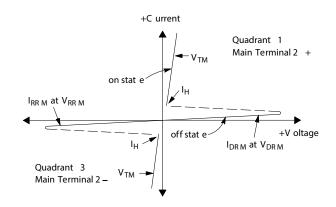


Figure 1. RMS Current Derating

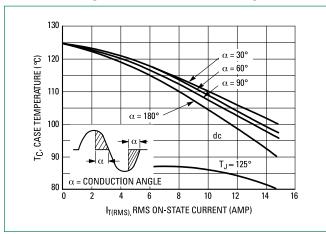


Figure 2. On-State Power Dissipation

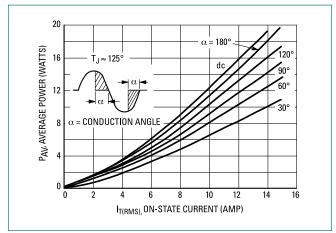


Figure 3. Typical Gate Trigger Voltage

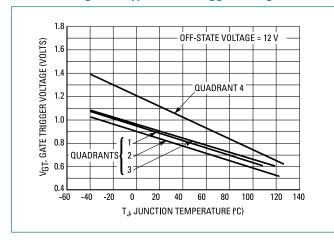


Figure 4. Typical Gate Trigger Current

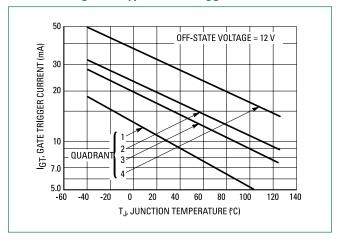




Figure 5. On-State Characteristics

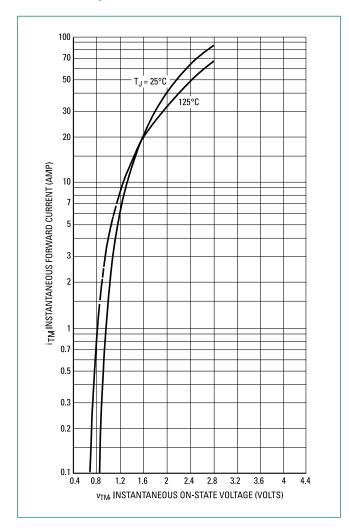


Figure 6. Typical Holding Current

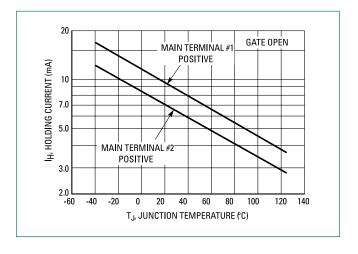


Figure 7. Maximum Non-Repetitive Surge Current

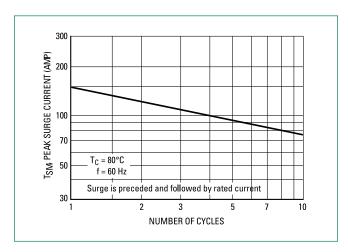
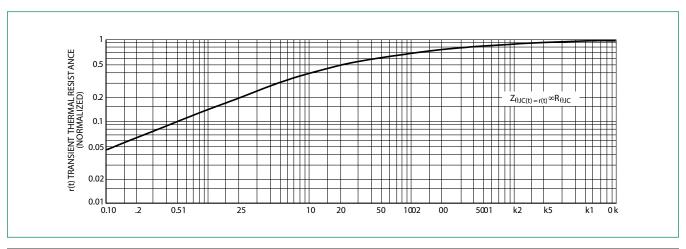


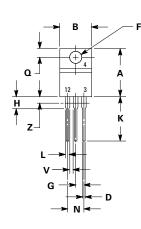
Figure 8. Thermal Response

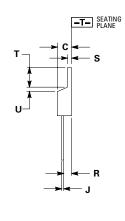




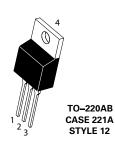
MAC15 Series TRIAC - 400V - 800V

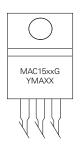
Dimensions





Part Marking System





xx =See Table on Page 2 Y =Year M =Month A =Assembly Site

XX =Lot Serial Code G =Pb-Free Package

D:	Inches Dim		Millin	neters
DIM	Min	Max	Min	Max
Α	0.590	0.620	14.99	15.75
В	0.380	0.420	9.65	10.67
С	0.178	0.188	4.52	4.78
D	0.025	0.035	0.64	0.89
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.41	2.67
Н	0.110	0.130	2.79	3.30
J	0.018	0.024	0.46	0.61
K	0.540	0.575	13.72	14.61
L	0.060	0.075	1.52	1.91
N	0.195	0.205	4.95	5.21
Q	0.105	0.115	2.67	2.92
R	0.085	0.095	2.16	2.41
S	0.045	0.060	1.14	1.52
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
V	0.045	-	1.15	-
Z	-	0.080	-	2.04

Pin Assignment			
1	Main Terminal 1		
2	Main Terminal 2		
3	Gate		
4	Main Terminal 2		

Ordering Information

Device	Device Device Marking Package		Shipping
MAC15-8G	MAC15-8		
MAC15-10G	MAC1510	TO 000 A D	
MAC15A6G	MAC15A6	TO-220AB (Pb-Free)	1000 Units/Box
MAC15A8G	MAC15A8	(1.5.1100)	
MAC15A10G	MAC15A10		



Disclaimer Notice - Information furnished is believed to be accurate and reliable. However, users should independently evaluate the suitability of and test each product selected for their own

^{1.} Dimensioning and tolerancing per ansi y14.5m, 1982.

Controlling dimension: inch.
 Dimension z defines a zone where all body and lead irregularities are allowed.

Mouser Electronics

Authorized Distributor

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Littelfuse:

MAC15A8G MAC15A6G MAC15-8G MAC15-10G MAC15A10G